(1) Publication number:

**0 369 347** A3

(12)

## **EUROPEAN PATENT APPLICATION**

(21) Application number: 89120874.6

(5) Int. Cl.5: **B41J 2/335**, **H01L 49/02** 

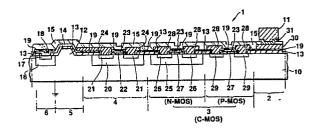
22) Date of filing: 10.11.89

Priority: 18.11.88 JP 290287/8828.03.89 JP 76237/89

- Date of publication of application:23.05.90 Bulletin 90/21
- ② Designated Contracting States:
  DE FR GB
- Bate of deferred publication of the search report: 24.10.90 Bulletin 90/43
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- (A) Thermal print head and a method for manufacturing the same.

(57) Disclosed is a thermal print head (1) in which heating resistance elements (14) are arranged with high density. The thermal print head comprises a head substrate (10), formed of a single-crystal silicon wafer, and a print driver circuit element (3, 4). The print driver circuit element (3, 4), which is formed by doping the head substrate (10) directly with an impurity, is composed of an MOS-FET. A FET used to form the single-crystal silicon substrate (10) has high electrical mobility, and serves to improve the operating speed of the thermal print head (1). Each heating resistance element (14), whose base material is polycrystalline silicon, is adjusted to a predetermined resistance value by being subjected to diffusion of an impurity. The resistance elements (14) are formed on a protuberance (12) which is formed on the head substrate (10). Thus, the portion of an insulating protective film (15) which corresponds to

the protuberance (12) projects outward from the rest, thereby ensuring contact with a printing sheet. An earthing diode (16, 17) or laminate structure is used for an earth line of each heating resistance elements (14) so that the resistance element (14) is situated close to a side edge portion of the head substrate (10).





## EUROPEAN SEARCH REPORT

EP 89 12 0874

ategory	Citation of document with i	ndication, where appropriate, ssages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.5)
	EP-A-129914 (TELETYPE ( * abstract; figure 2 *	CORP.)	1	H01L49/02 B41J2/335
- }			1	
	US-A-4429321 (CANON K.# * abstract; figure 1 * 		1	
			5	TECHNICAL FIELDS
		·		SEARCHED (Int. Cl.5)
				H01L
				B41J
	The present search report has l	been drawn up for all claims		
Place of search		Date of completion of the search		Examiner
	THE HAGUE	23 AUGUST 1990	PEL	SERS L.
	CATEGORY OF CITED DOCUME	CNTS T: theory or princi E: earlier patent do after the filing nother D: document cited L: document cited	ple underlying th ocument, but pub	e invention lished on, or

- O: non-written disclosure
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